



30V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)}	I _D T _A = +25°C
	760mΩ @ V _{GS} = 4.5V	0.65A
30V	930mΩ @ V _{GS} = 2.5V	0.58A
	1500mΩ @ V _{GS} = 1.8V	0.45A

Description

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Load switch
- Portable applications
- Power Management Functions

Features

- 0.4mm ultra low profile package for thin application
- 0.48mm² package footprint, 16 times smaller than SOT23
- Low V_{GS(th)}, can be driven directly from a battery
- Low R_{DS(on)}
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

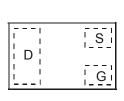
Mechanical Data

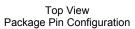
- Case: X2-DFN0806-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.00043 grams (approximate)

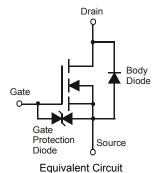












Ordering Information (Note 4)

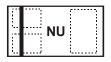
Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN3900UFA-7B	NU	7	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

DMN3900UFA-7B



Top View Bar Denotes Gate and Source Side

NU = Product Type Marking Code



Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±8	1 v
		(Note 6)	I _D	0.65	A
Continuous Drain Current	V _{GS} = 4.5V	T _A = +70°C (Note 6)		0.52	
		(Note 5)		0.55	
Pulsed Drain Current		(Note 7)	I _{DM}	2.5	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

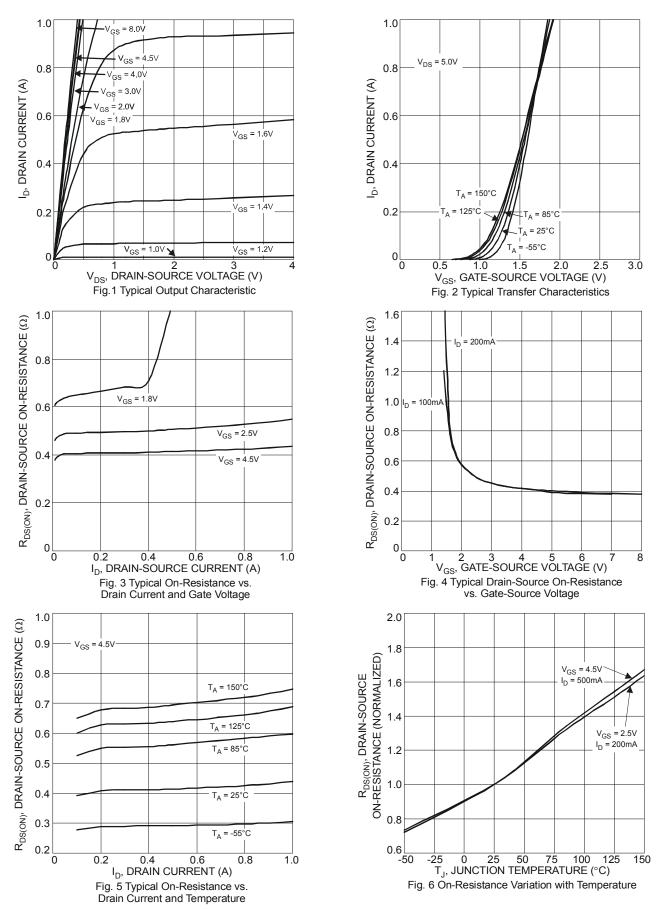
Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)	0	490	- mW	
Power Dissipation	(Note 5)	P _D	390		
Thermal Decistance, Junction to Ambient	(Note 6)	0	255	°C/W	
Thermal Resistance, Junction to Ambient	(Note 5)	R _{0JA}	327		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

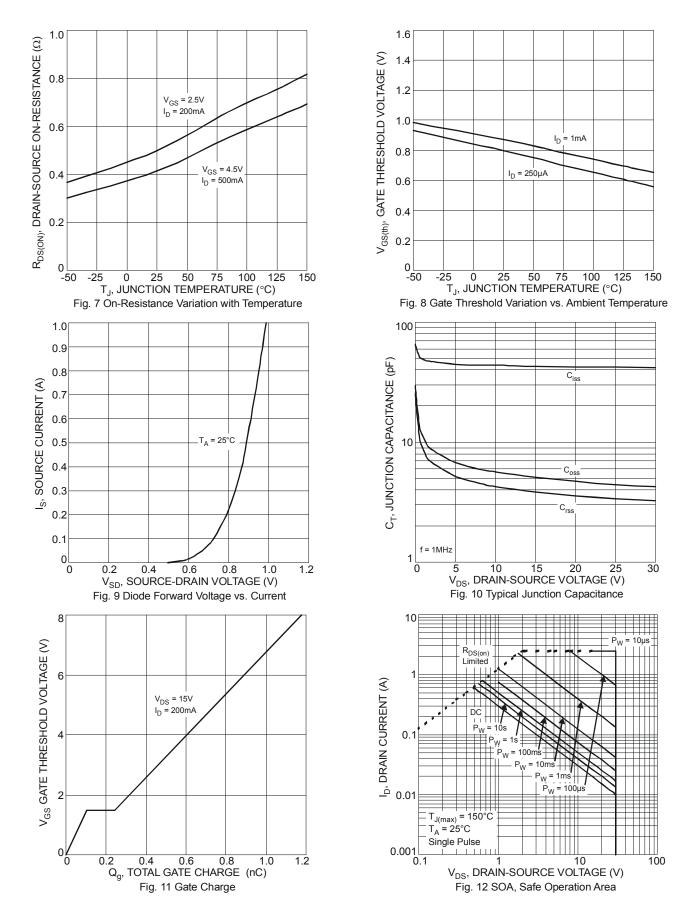
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	V _{DS} = 30V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	3	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	0.45	_	0.95	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
			400	760		$V_{GS} = 4.5V, I_D = 200mA$	
Static Drain-Source On-Resistance	R _{DS(on)}	_	480	930	mΩ	$V_{GS} = 2.5V, I_D = 100mA$	
			617	1500		V _{GS} = 1.8V, I _D = 75mA	
Forward Transfer Admittance	Y _{fs}	40	_	_	mS	V_{DS} = 3V, I_D = 10mA	
Diode Forward Voltage (Note 8)	V _{SD}		0.7	1.2	V	V _{GS} = 0V, I _S = 300mA	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}		42.2	_	pF		
Output Capacitance	Coss	_	4.5	_	pF	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	3,4	_	pF	1 - 1.00112	
Gate Resistance	R_g	_	468	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	0.7	_	nC		
Gate-Source Charge	Q _{gs}	_	0.11	_	nC	$V_{GS} = 4.5V, V_{DS} = 15V,$ $I_{D} = 200 \text{mA}$	
Gate-Drain Charge	Q _{gd}	_	0.15	_	nC		
Turn-On Delay Time	t _{D(on)}	_	10.5	_	ns		
Turn-On Rise Time	t _r	_	7.8	_	ns	V_{DS} = 10V, I_{D} = 200mA V_{GS} = 4.5V, R_{G} = 6 Ω	
Turn-Off Delay Time	t _{D(off)}	_	80.6	_	ns		
Turn-Off Fall Time	t _f	_	23.4	_	ns		

- 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.
- 5. Device mounted on FR-4 PCB, with minimum recommended pad layout,
 6. Device mounted on FR-4 PCB, with minimum recommended pad layout, except the device measured at t ≤ 10 sec.
 7. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.
 8. Short duration pulse test used to minimize self-heating effect.
 9. Guaranteed by design. Not subject to production testing

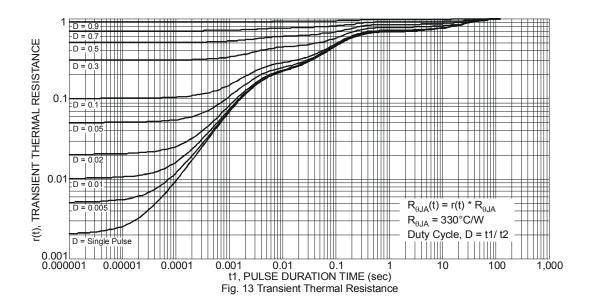






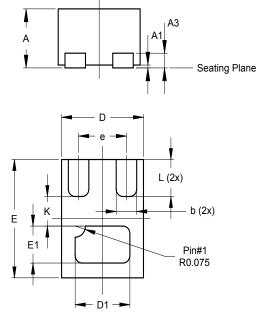






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

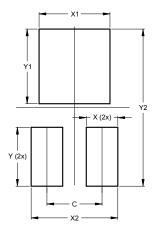


X2-DFN0806-3					
Dim	Min	Max	Тур		
Α	0.375	0.40	0.39		
A1	0	0.05	0.02		
A3	-	-	0.10		
b	0.10	0.20	0.15		
D	0.55	0.65	0.60		
D1	0.35	0.45	0.40		
Е	0.75	0.85	0.80		
E1	0.20	0.30	0.25		
е	-	-	0.35		
K	-	-	0.20		
L	0.20	0.30	0.25		
All Dimensions in mm					



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)				
С	0.350				
X	0.200				
X1	0.450				
X2	0.550				
Υ	0.375				
Y1	0.475				
Y2	1.000				

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